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SI-8000GL Series Compact, Separate Excitation Step-down Switching Mode

Paramotor Symbo

Absolute Maximum Ratings

Features

• DIP 8 pin package

- Output current: 1.5A
- High efficiency: 86% (at VIN = 20V, Io = 1A, Vo = 5V)

 Capable of downsize a choke-coil due to IC's high switching frequency (250kHz). (Compared with conventional Sanken devices)

• The output-voltage-variable type can vary its output voltage from 1V to 14V because of its low reference voltage (Vref) of 1V.

Wide Input Voltage Range (8 to 50V)

- Output ON/OFF available
- Built-in overcurrent protection and thermal protection circuits

Applications

- Onboard local power supplies
- OA equipment

· For stabilization of the secondary-side output voltage of switching power supplies

Recommended Operating Conditions

Parameter	Symbol	Ratings SI-8010GL	Unit
DC Input Voltage Range	VIN	(8 or Vo+3)*1 to 50	V
Output Voltage Range	Vo	1 to 14	V
Output Current Range*2	lo	0.02 to 1.5 ^{°2}	A
Operating Junction Temperature Range	Tjop	-30 to +125	°C
Operating Temperature Range	Top	-30 to +125	°C

*1: The minimum value of an input voltage range is the higher of either 8V or Vo+3V.

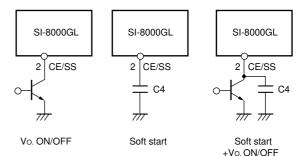
*2: Please be sure to let the output current run more than 20 mA. When using by less than 20 mA, there is a possibility that the output voltage becomes unstable.

■Electrical Characteristics

			Ratings				
Parameter	Parameter	Symbol	SI-8010GL (Variable type)			Unit	
		min.	typ.	max.			
Reference Voltage	altago	VREF	0.97	1.00	1.03	V	
	Conditions	VIN=12V, Io=1A			V		
Efficiency		Eff		86		~ %	
		Conditions	VIN=20V, Io=1A, Vo=5V				
0 W K E	requerey	Fosc		250		kHz	
Oscillation Frequency		Conditions		VIN=12V, IO=1A		KHZ	
ino Rogulat	tion			20	40	mV	
Line Regulation	uon	Conditions		VIN=10 to 30V, Io=1A		inv	
and Pagula	ation			10	30	mV	
Load Regulation	Conditions		VIN=12V, Io=0.1 to 1.5A		IIIV		
Temperature Coefficient of Reference Voltage		ΔVREF/ΔTa		±0.5		mV/°C	
Overcurrent Protection Starting Current		ls	1.6			A	
		Conditions		VIN=12V		~	
Quiescent Circuit Current		lq		7		mA	
		Conditions		VIN=12V, IO=0A			
Circuit Current at Output OFF		lq(OFF)			400		
		Conditions	VIN=12V, VONIOFF=0.3V			μΑ	
CE/SS [*] Terminal	Low Level Voltage	VSSL			0.5	V	
	Terminal Outflow	Issl			50	μΑ	
	Current at Low Voltage	Conditions		Vssl=0V			

*: Pin 2 is the CE/SS pin. Soft start at power on can be performed with a capacitor connected to this pin. The output can also be turned ON/OFF with this pin. The output is stopped by setting the voltage of this pin to VssL or lower. CE/SS-pin voltage can be changed with an open-collector drive circuit of a transistor.

When using both the soft-start and ON/OFF functions together, the discharge current from C4 flows into the ON/OFF control transistor. Therefore, limit the current securely to protect the transistor if C3 capacitance is large. The CE/SS pin is pulled up to the power supply in the IC, so applying the external voltage is prohibited.



DC Input Voltage	VIN	53	V
Power Dissipation	Pd*1	1	W
Junction Temperature	Tj	+125	°C
Storage Temperature	Tstg	-40 to +125	°C
Thermal Resistance (junction to case)	θj-c	28	°C/W
Thermal Resistance (junction to ambient air)	hetaj-a	100	°C/W

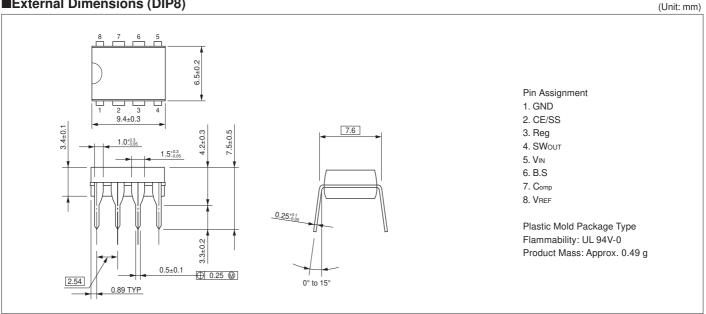
Potipas

LInit

(Ta=25°C)

*1: Limited by thermal protection.

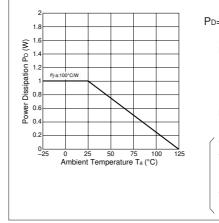
External Dimensions (DIP8)



■Block Diagram

SI-8010GL P.REG UVLC CP GN

■Ta-PD Characteristics

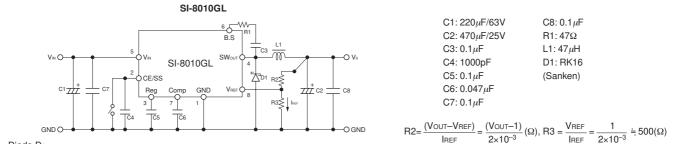


=Vo•lo	$\left(rac{100}{\eta\chi} - 1 ight) - V_F \cdot Io\left(1 - rac{V_O}{V_{IN}} ight)$		
Note 1:	The efficiency depends on the input volt- age and the output current. Therefore, ob- tain the value from the efficiency graph and substitute the percentage in the formula above.		
Note 2:	Thermal design for D1 must be considered separately.		
Vo : Output voltage ViN : Input voltage			

lo : Output current

- $\eta\chi$: Efficiency
- VF : Diode D1 forward voltage
 - RK16…0.4V(Io=1A)

■Typical Connection Diagram



Diode D1

· Be sure to use a Schottky-barrier diode as D1. If other diodes like fast recovery diodes are used, IC may be destroyed because of the reverse voltage generated by the recovery voltage or ON voltage.

Choke coil L1 • If the winding resistance of the choke coil is too high, the efficiency may drop below the rated value.

• As the overcurrent protection starting current is approx. 2.5 A, take care concerning heat radiation from the choke coil caused by magnetic saturation due to overload or short-circuited load.

Capacitor C1, C2

• As large ripple currents flow through C1 and C2, use high-frequency and low-impedance capacitors aiming for switching-mode-power-supply use. Especially when the impedance of C2 is high, the switching waveform may become abnormal at low temperatures. For C2, do not use a capacitor with an extremely low equivalent series resistance (ESR) such as an OS capacitor or a tantalum capacitor, which may cause an abnormal oscillation. Resistors R2, R3

• R2 and R3 are the resistors to set the output voltage. Set their values so that IREF becomes approx. 2 mA. Obtain R2 and R3 values by the following formula above.

* To create the optimum operating conditions, place the components as close as possible to each other.